

Product specification

BYC10-600CT

Rectifier diode ultrafast, low switching loss

FEATURES

• Dual diode

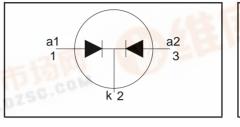
- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in
- associated MOSFET

APPLICATIONS

- Active power factor correction
- Half-bridge lighting ballasts
 Half-bridge/ full-bridge switched
- mode power supplies.

The BYC10-600CT is supplied in the SOT78 (TO220AB) conventional leaded package.

SYMBOL



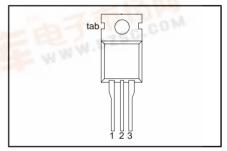
PINNING

PIN DESCRIPTION 1 anode 1 2 cathode 3 anode 2 cathode tab

QUICK REFERENCE DATA

 $V_{R} = 600 V$ $V_F \le 1.75 \text{ V}$ $I_{O(AV)} = 10 \text{ A}$ $t_{rr} = 19 \text{ ns} (typ)$

SOT78 (TO220AB)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	Peak repetitive reverse voltage	1 64 192	The Walt	600	V
V _{RWM}	Crest working reverse voltage		AN 21	600	V
V _R	Continuous reverse voltage	$T_{mb} \leq 110 \ ^{\circ}C$	-	500	V
I _{O(AV)}	Average output current (both diodes conducting)	T_{mb} ≤ 110 °C δ = 0.5; with reapplied V _{RRM(max)} ; T_{mb} ≤ 50 °C ¹	-	10	A
I _{FRM}	Repetitive peak forward current	δ = 0.5; with reapplied V _{RRM(max)} ; T _{mb} \leq 50 °C ¹	-	10	A
FSM	Non-repetitive peak forward	t = 10 ms	-	40	A
FSIM	current per diode	t = 8.3 ms	-	44	A
		sinusoidal; $T_j = 150^{\circ}C$ prior to surge with reapplied $V_{RWM(max)}$		17.16	
T _{sta}	Storage temperature	i i i i i i i i i i i i i i i i i i i	-40	150	°C
T _{stg} T _i	Operating junction temperature		da-TI	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	mounting base	per diode both diodes in free air.	- -	- - 60	2.5 2.2 -	K/W K/W K/W



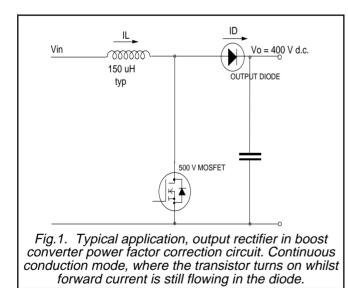
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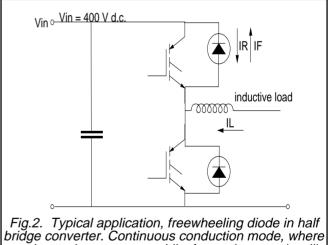
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ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C, per diode unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_{\rm F} = 5 \text{ A}; T_{\rm L} = 150^{\circ} \text{C}$	-	1.4	1.75	V
		I _F = 10 Å; Τ _j = 150°C I _F = 5 A;	-	1.75 2.0	2.2 2.8	V
I _R	Reverse current	$\dot{V}_{R} = 600 \text{ V}$	-	2.0	100	μA
K		V _R = 500 V; T _j = 100 °C	-	0.9	3.0	mΑ
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s}$	-	30	50	ns
t _{rr}	Reverse recovery time	$I_{F} = 5 \text{ A}; V_{R} = 400 \text{ V};$ $dI_{e}/dt = 500 \text{ A}/\mu \text{s}$	-	19	-	ns
t _{rr}	Reverse recovery time	$I_{F} = 5 \text{ A}; V_{R} = 400 \text{ V};$	-	25	30	ns
		$dI_{F}/dt = 500 \text{ A}/\mu\text{s}; T_{j} = 125^{\circ}\text{C}$				
l _{rrm}	Peak reverse recovery current	I _F = 5 A; V _R = 400 V; dI _F /dt = 50 A/μs; T _i = 125°C	-	0.7	3	А
l _{rrm}	Peak reverse recovery current	$I_F = 5 \text{ A}; V_R = 400 \text{ V};$	-	8	11	А
		$dI_{F}/dt = 500 \text{ A}/\mu \text{s}; T_{j} = 125^{\circ}\text{C}$				
V _{fr}	Forward recovery voltage	$I_F = 10 \text{ A}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	9	11	V



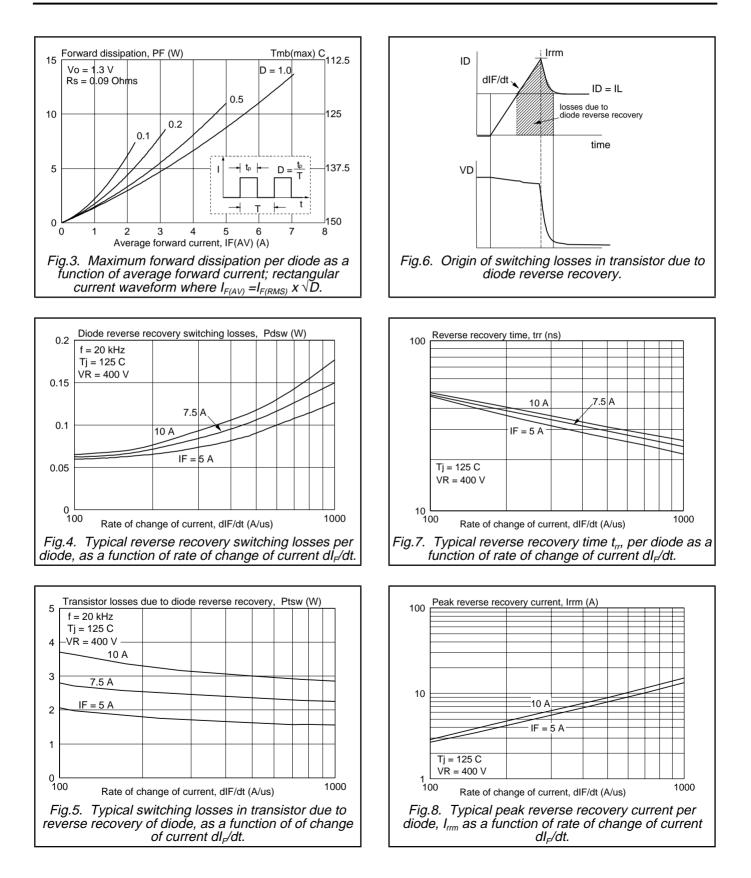


bridge converter. Continuous conduction mode, where each transistor turns on whilst forward current is still flowing in the other bridge leg diode.

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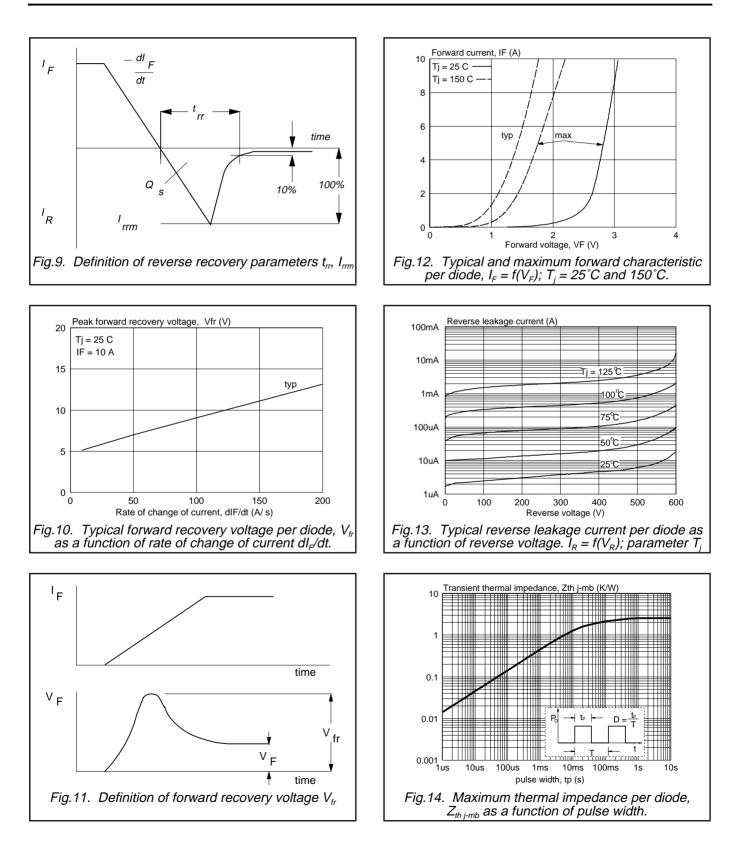
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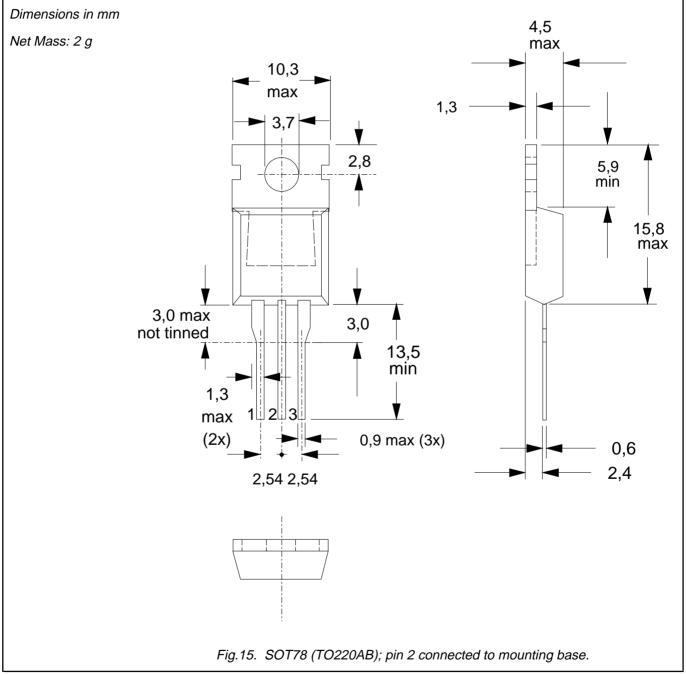
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MECHANICAL DATA



Notes

Refer to mounting instructions for SOT78 (TO220) envelopes.
 Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status			
Objective specification	ctive specification This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			
Where application information is given, it is advisory and does not form part of the specification.			
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